Silicon Epitaxial Planar Small Signal Diode





Description

These diodes are also available in other case styles including the DO-35 case with the type designation IN4148, the MiniMELF case with the type designation LL4148 and the MicroMELF case with the type designation MCL4148.

Features

SOD 123 package

· Fast switching

Reverse voltage: 100 VoltsForward current: 150mA

Absolute Maximum Ratings (T_A = 25°C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	VRM	100	V
Reverse Voltage	VR	75	V
Average Rectified Current Half Wave Rectification With Resistive Load f ≥ 50Hz (Note 1)	lf(AV)	150	mA
Non-repetitive Peak Forward Surge Current @ = 1.0µs	IFSM	2	Α
Power Dissipation (Note 1)	Po	400	mW
Thermal Resistance Junction to Ambient Air (Note 1)	Reja	450	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Electrical Characteristics (TA = 25°C)

Parameter	Symbol	Test Conditions	Min.	Max.	Unit
Forward Voltage	VF	IF = 10mA	-	1	V
Reverse Current	lR	V _R = 20V V _R = 75V V _R = 20V, T _J = 150°C	- -	25 5 50	nΑ μΑ μΑ
Capacitance	Ст	V _F = V _R = 0V	-	4	pF
Reverse Recovery Time	trr	from I _F = 10mA to I _R = 1mA, V_R = 6V, R_L = 100 Ω	-	4	ns
Voltage rise when switching ON (tested with 50mA pulse)	VFR	tp = 0.1us, rise time <30ns, fp = (5 to 100)kHz	-	2.5	V
Rectification Efficiency	η _V	f = 100MHz, VRF = 2V	0.45	-	-

Note: 1. Valid provided that electrodes are kept at ambient temperature.

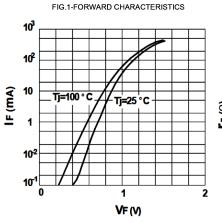
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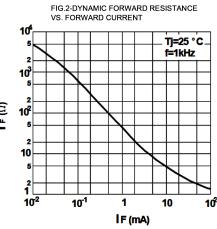


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Rating and Characteristic Curves





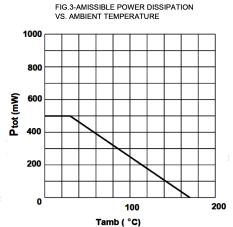
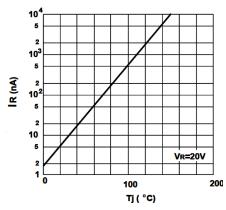
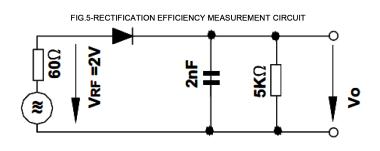
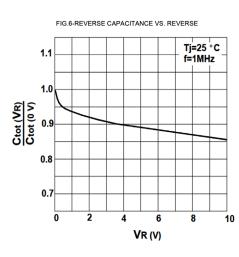
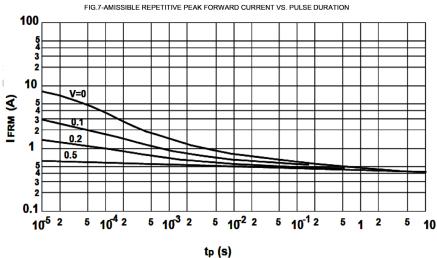


FIG.4-LEAKAGE CURRENT VS. JUNVTION TEMPERATURE









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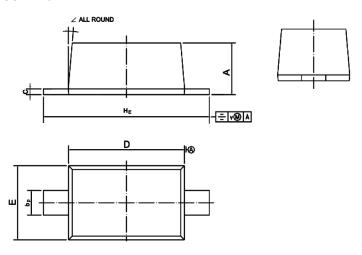


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Dimensions:

SOD-123



Unit	Α	bp	С	D	E	HE	V	4
mm	1.15 1.05	0.6 0.5	0.135 0.127	2.7 2.6	1.65 1.55	3.9 3.7	0.2	5°

Part Number Table

Description	Part Number		
Silicon Epitaxial Planar Small Signal Diode	1N4148W+		

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